

# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

D2484, MARCH 1979—REVISED MARCH 1989

- Low Input Offset Voltage . . . 0.5 mV Max
- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- High Input Impedance . . . JFET-Input Stage
- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 18 V/ $\mu$ s Typ
- Low Total Harmonic Distortion . . . 0.003% Typ

## description

These JFET-input operational amplifiers incorporate well-matched high-voltage JFET and bipolar transistors in a monolithic integrated circuit. They feature low input offset voltage, high slew rate, low input bias and offset currents, and low temperature coefficient of input offset voltage. Offset-voltage adjustment is provided for the TL087 and TL088.

The M-suffix devices are characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The I-suffix devices are characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ , and the C-suffix devices are characterized for operation  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ .

## AVAILABLE OPTIONS

TA	TYPE	V <sub>IO</sub> MAX AT 25°C	PACKAGE				
			SMALL OUTLINE (D)	CERAMIC DIP (JG)	METAL CAN (L)	PLASTIC DIP (P)	FLAT (U)
$0^{\circ}\text{C}$ to $70^{\circ}\text{C}$	Single	0.5 mV 1 mV	TL087CD TL088CD	TL087CJG TL088CJG	TL087CL TL088CL	TL087CP TL088CP	
	Dual	0.5 mV 1 mV	TL287CD TL288CD	TL287CJG TL288CJG	TL287CL TL288CL	TL287CP TL288CP	
$-40^{\circ}\text{C}$ to $85^{\circ}\text{C}$	Single	0.5 mV 1 mV	TL087ID TL088ID	TL087IJG TL088IJG	TL087IL TL088IL	TL087IP TL088IP	
	Dual	0.5 mV 1 mV	TL287ID TL288ID	TL287IJG TL288IJG	TL287IL TL288IL	TL287IP TL288IP	
$-55^{\circ}\text{C}$ to $125^{\circ}\text{C}$	Single	1 mV		TL088MJG	TL088ML		TL088MU
	Dual	1 mV		TL288MJG	TL288ML		TL288MU

The D package is available taped and reeled. Add the suffix R to the device type (e.g., TL087CDR).

**PRODUCTION DATA** documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

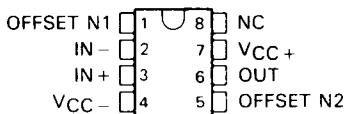
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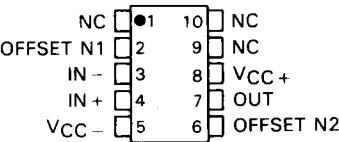
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# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

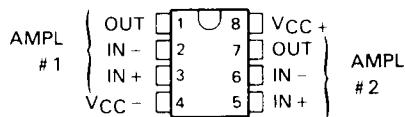
**TL087, TL088  
D, JG, OR P PACKAGE  
(TOP VIEW)**



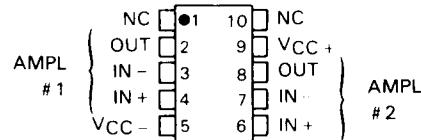
**TL088M  
U PACKAGE  
(TOP VIEW)**



**TL287, TL288  
D, JG, OR P PACKAGE  
(TOP VIEW)**

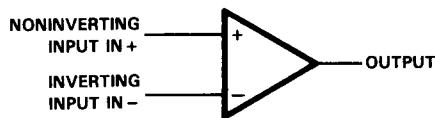


**TL288M  
U PACKAGE  
(TOP VIEW)**

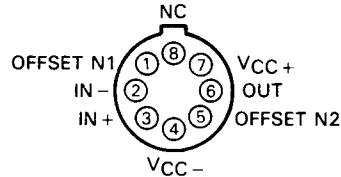


NC—No internal connection

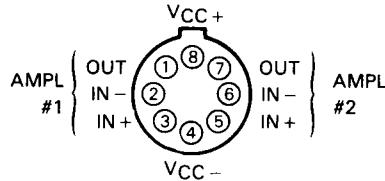
## symbol (each amplifier)



**TL087, TL088  
L PACKAGE  
(TOP VIEW)**



**TL287, TL288  
L PACKAGE  
(TOP VIEW)**



Pin 4 (L Package) is in electrical contact with the case  
NC—No internal connection

**TL087, TL088, TL287, TL288**  
**JFET-INPUT OPERATIONAL AMPLIFIERS**

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

	TL088M TL288M	TL087I TL088I TL287I TL288I	TL087C TL088C TL287C TL288C	UNIT
Supply voltage, $V_{CC+}$ (see Note 1)	18	18	18	V
Supply voltage, $V_{CC-}$ (see Note 1)	-18	-18	-18	V
Differential input voltage (see Note 2)	$\pm 30$	$\pm 30$	$\pm 30$	V
Input voltage (see Notes 1 and 3)	$\pm 15$	$\pm 15$	$\pm 15$	V
Input current, $I_I$ (each input)	$\pm 1$	$\pm 1$	$\pm 1$	mA
Output current, $I_O$ (each output)	$\pm 80$	$\pm 80$	$\pm 80$	mA
Total $V_{CC+}$ terminal current	160	160	160	mA
Total $V_{CC-}$ terminal current	-160	-160	-160	mA
Duration of output short circuit (see Note 4)	unlimited	unlimited	unlimited	
Continuous total dissipation		See Dissipation Rating Table		
Operating free-air temperature range	-55 to 125	-25 to 85	0 to 70	°C
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	°C
Lead temperature 1.6 mm (1/16 inch) from case for 60 seconds	JG, L, or U package	300	300	300
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	D or P package		260	260

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{CC+}$  and  $V_{CC-}$ .  
 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.  
 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.  
 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ C$	DERATING FACTOR	$T_A = 70^\circ C$	$T_A = 85^\circ C$	$T_A = 125^\circ C$
	POWER RATING	ABOVE $T_A - 25^\circ C$	POWER RATING	POWER RATING	POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	N/A
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
L	650 mW	5.2 mW/°C	416 mW	338 mW	130 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW	N/A
U	675 mW	5.4 mW/°C	432 mW	351 mW	135 mW

**recommended operating conditions**

	M-SUFFIX			I-SUFFIX			C-SUFFIX			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, $V_{CC}$	$\pm 5$	$\pm 15$		$\pm 5$	$\pm 15$		$\pm 5$	$\pm 15$		V
Common-mode input voltage, $V_{IC}$	$V_{CC\pm} = \pm 5$ V	-1	4	-1	4	-1	4			V
	$V_{CC\pm} = \pm 15$ V	-11	11	-11	11	-11	11			V
Input voltage, $V_I$	$V_{CC\pm} = \pm 5$ V	-1	4	-1	4	-1	4			V
	$V_{CC\pm} = \pm 15$ V	-11	11	-11	11	-11	11			V
Operating free-air temperature, $T_A$	-55	125	-40	85	0	70				°C



# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

**electrical characteristics,  $V_{CC\pm} = \pm 15$  V**

PARAMETER	TEST CONDITIONS <sup>†</sup>	TL088M				TL087I				TL087C			
		TL288M		TL288I		TL287I		TL288I		TL088C		TL287C	
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX
$V_{IO}$ Input offset voltage	$R_S = 50 \Omega$ , $V_O = 0$ , $T_A = 25^\circ C$	TL087, TL287			0.1	0.1	0.5	0.1	0.1	0.15			
$V_{IO}$ Input offset voltage	$R_S = 50 \Omega$ , $V_O = 0$ , $T_A = \text{full range}$	TL088, TL288	0.1	3	0.1	1	1	0.1	0.1	1	1	mV	
$\alpha V_{IO}$ Temperature coefficient of input offset voltage	$R_S = 50 \Omega$ , $T_A = 25^\circ C$ to MAX	10						2		1.5			
$I_{IO}$ Input offset current	$T_A = 25^\circ C$		5		5	100		8		8			$\mu A/\circ C$
$I_B$ Input bias current <sup>‡</sup>	$T_A = 25^\circ C$		25		3			3		2			nA
$V_{ICR}$ Common-mode input voltage range	$T_A = 25^\circ C$		30		30	200		30	200	30	200		pA
$V_{OPP}$ Maximum-peak-to-peak output voltage swing	$T_A = 25^\circ C$ , $R_L = 10 k\Omega$	24	27	24	27	24	27	24	27	24	27		V
$A_{VD}$ Large-signal differential voltage amplification	$R_L \geq 2 k\Omega$ , $T_A = 25^\circ C$	$R_L \geq 10 k\Omega$	24	24	24	24	24	24	24	24	24		V
$B_1$ Unity-gain bandwidth	$R_L \geq 2 k\Omega$ , $T_A = 25^\circ C$	$R_L \geq 2 k\Omega$	20	20	20	20	20	20	20	20	20		V/mV
$f_I$ Input resistance	$T_A = 25^\circ C$		50	105	50	105	50	105	50	105	50	105	MHz
CMRR ratio	$R_S = 50 \Omega$ , $V_{ICR} \text{ min.}, T_A = 25^\circ C$	$V_O = \pm 10 V$ ,	25		25		25		25		25		
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{CC\pm}/\Delta V_{IO}$ )	$R_S = 50 \Omega$ , $T_A = 25^\circ C$	$V_{CC\pm} = \pm 9 V$ to $\pm 15 V$ ,	80	93	80	93	80	93	80	93	80	93	dB
$I_{CC}$ (per amplifier)	No load, $T_A = 25^\circ C$	$V_O = 0$ ,	2.6	2.8	2.6	2.8	2.6	2.8	2.6	2.8	2.6	2.8	mA

<sup>†</sup>All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for  $T_A$  is  $-55^\circ C$  to  $125^\circ C$  for TL-88M;  $-40^\circ C$  to  $85^\circ C$  for TL-8;

<sup>‡</sup>Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

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JFET-INPUT OPERATIONAL AMPLIFIERS**

**operating characteristics  $V_{CC} = \pm 15$  V,  $T_A = 25^\circ\text{C}$**

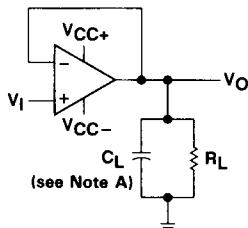
PARAMETER	TEST CONDITIONS	TL088M, TL288M			TL087I, TL087C TL088I, TL088C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_I = 10$ V, $R_L = 2$ k $\Omega$ , $C_L = 100$ pF, $A_{VD} = 1$		18		8	18		V/ $\mu$ s
$t_r$ Rise time	$V_I = 20$ mV, $R_L = 2$ k $\Omega$ ,		55		55			ns
Overshoot factor	$C_L = 100$ pF, $A_{VD} = 1$		25%		25%			
$V_n$ Equivalent input noise voltage	$R_S = 100$ $\Omega$ , $f = 1$ kHz		19		19			nV/ $\sqrt{\text{Hz}}$



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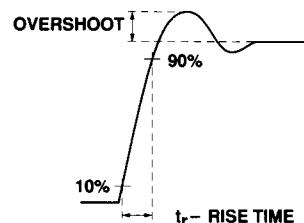
# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

## PARAMETER MEASUREMENT INFORMATION

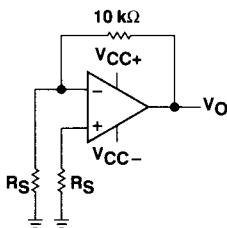


NOTE A:  $C_L$  includes fixture capacitance.

**FIGURE 1. SLEW RATE, RISE/FALL TIME,  
AND OVERSHOOT TEST CIRCUIT**



**FIGURE 2. RISE TIME AND OVERSHOOT  
WAVEFORM**



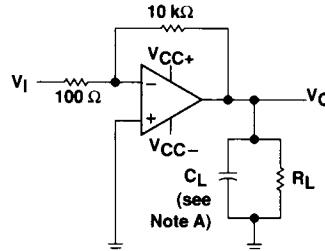
**FIGURE 3. NOISE VOLTAGE TEST CIRCUIT**

### typical values

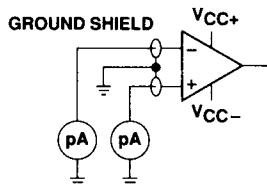
Typical values as presented in this data sheet represent the median (50% point) of device parametric performance.

### input bias and offset current

At the picoamp bias current level typical of these JFET operational amplifiers, accurate measurement of the bias current becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied, but with no device in the socket. The device is then inserted in the socket and a second test that measures both the socket leakage and the device input bias current is performed. The two measurements are then subtracted algebraically to determine the bias current of the device.



**FIGURE 4. UNITY-GAIN BANDWIDTH AND  
PHASE MARGIN TEST CIRCUIT**



**FIGURE 5. INPUT BIAS AND OFFSET  
CURRENT TEST CIRCUIT**

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**TYPICAL CHARACTERISTICS**

**table of graphs**

		<b>FIGURE</b>
$\alpha V_{IO}$	Temperature coefficient of input offset voltage	6, 7
$I_{IO}$	Input offset current	8
$I_{IB}$	Input bias current	9 8
$V_I$	Common-mode input voltage range limits	10 11
$V_{ID}$	Differential input voltage	12
$V_{OM}$	Maximum peak output voltage swing	13 17 vs Frequency vs Temperature 14, 15, 16 18
$A_{VD}$	Differential voltage amplification	19 20 vs Frequency vs Temperature 21
$z_o$	Output impedance	24 vs Frequency
CMRR	Common-mode rejection ratio	22 vs Frequency vs Temperature 23
$k_{SVR}$	Supply-voltage rejection ratio	25 vs Temperature
$I_{OS}$	Short-circuit output current	26 vs $V_{CC}$ 27 vs Time vs Temperature 28
$I_{CC}$	Supply current	29 vs $V_{CC}$ vs Temperature 30
SR	Slew Rate	31 vs $R_L$ vs Temperature 32
	Overshoot factor	33 vs $C_L$
$V_n$	Equivalent input noise voltage	34 vs Frequency
THD	Total harmonic distortion	35 vs Frequency
$B_1$	Unity-gain bandwidth	36 vs $V_{CC}$ vs Temperature 37
$\phi_m$	Phase margin	38 vs $V_{CC}$ vs $C_L$ vs Temperature 39 40
	Phase shift	20 vs Frequency
	Pulse response	41 Small-signal Large-signal 42

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## TYPICAL CHARACTERISTICS<sup>†</sup>

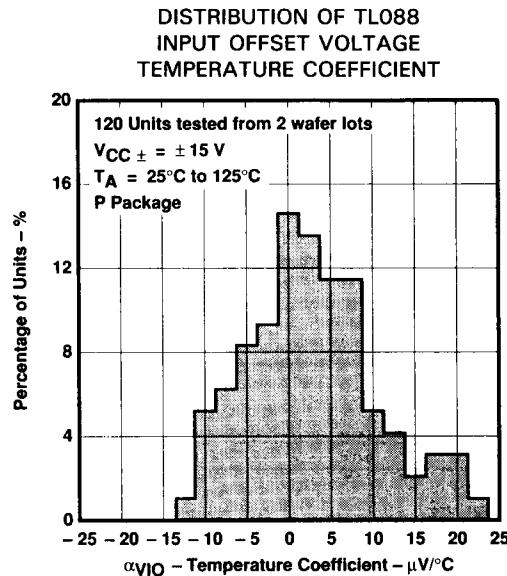


FIGURE 6

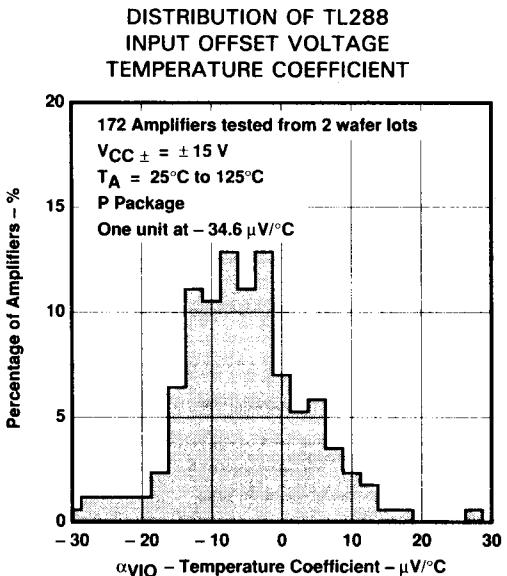


FIGURE 7

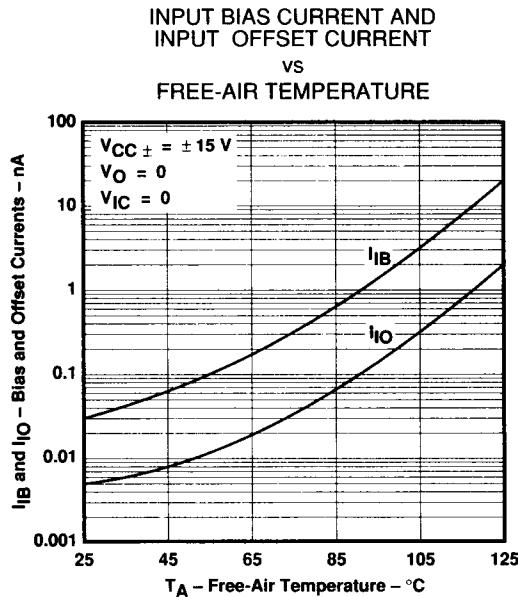


FIGURE 8

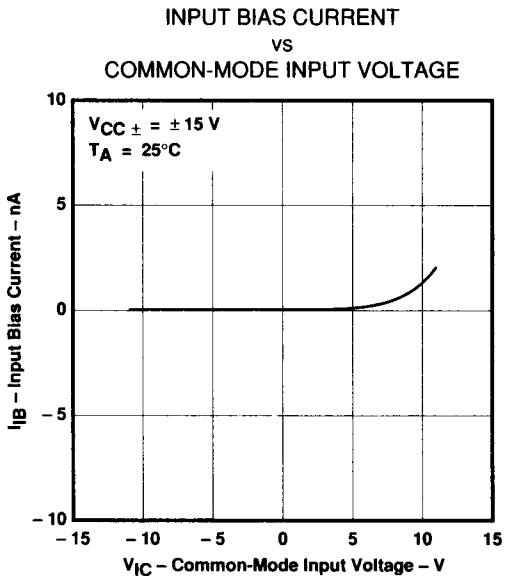
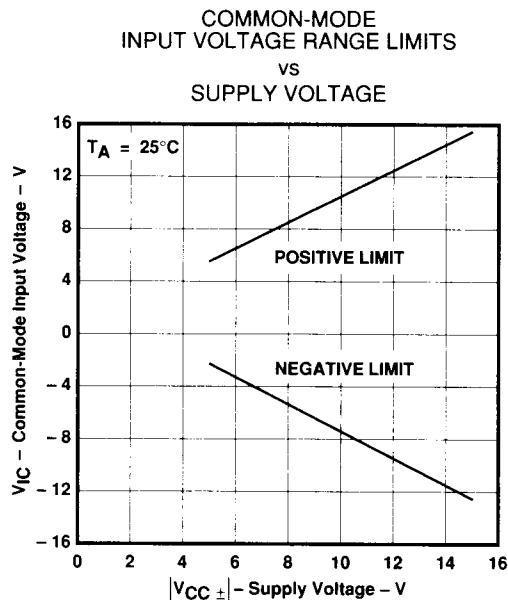


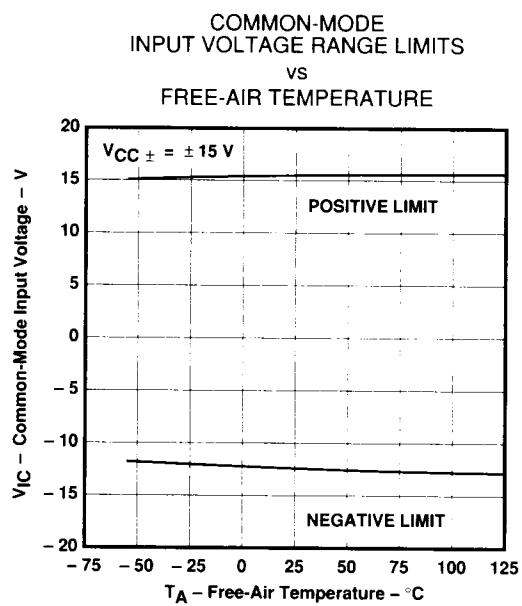
FIGURE 9

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

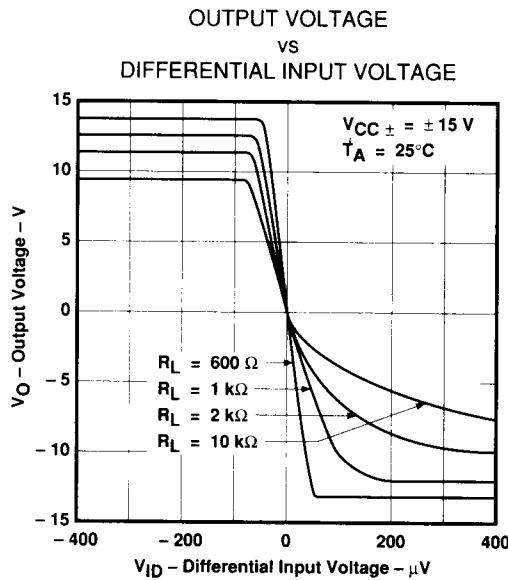
**TYPICAL CHARACTERISTICS<sup>†</sup>**



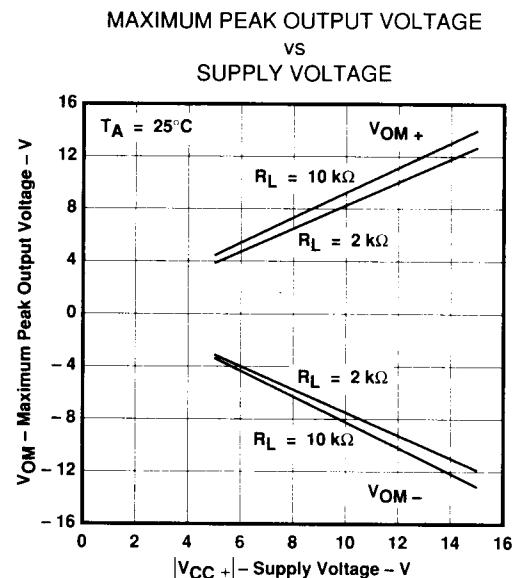
**FIGURE 10**



**FIGURE 11**



**FIGURE 12**



**FIGURE 13**

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

## TYPICAL CHARACTERISTICS<sup>†</sup>

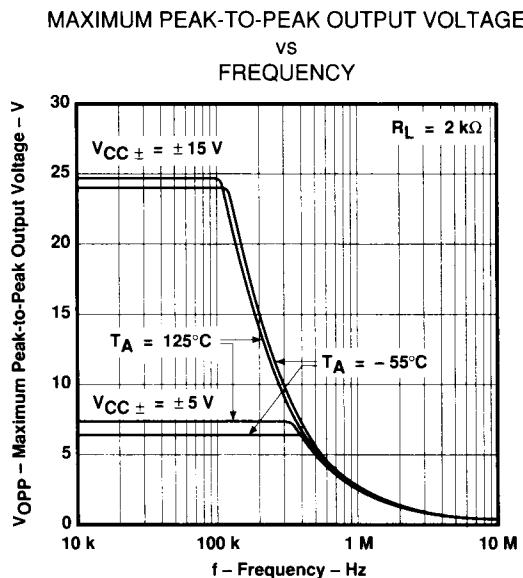


FIGURE 14

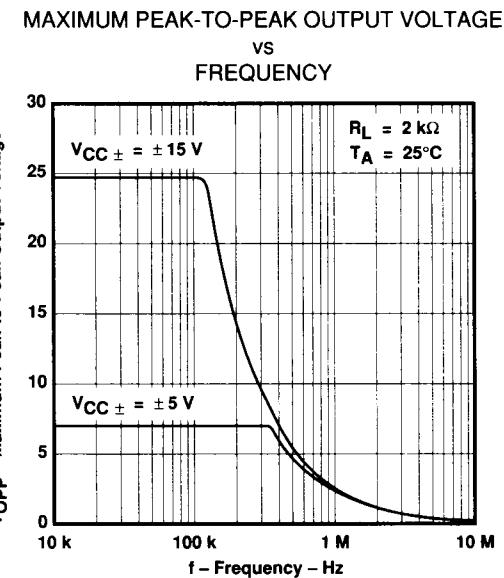


FIGURE 15

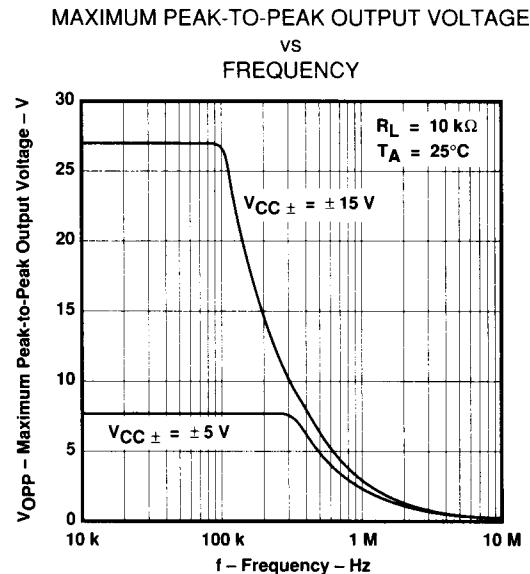


FIGURE 16

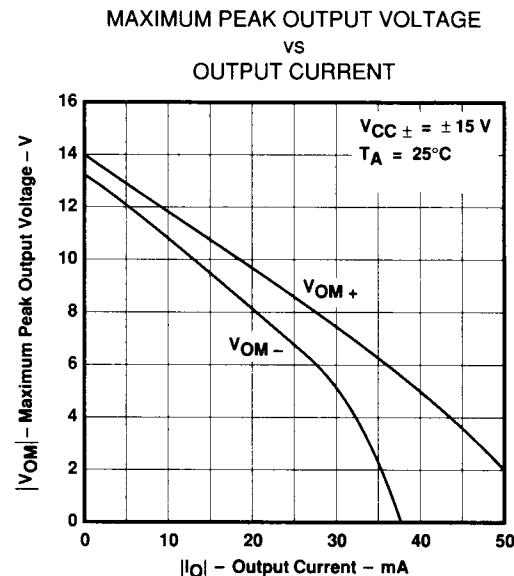


FIGURE 17

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

**TYPICAL CHARACTERISTICS<sup>†</sup>**

MAXIMUM PEAK OUTPUT VOLTAGE  
 VS  
 FREE-AIR TEMPERATURE

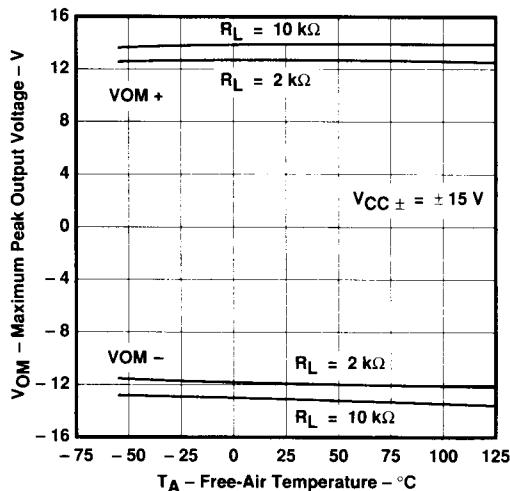


FIGURE 18

LARGE-SIGNAL VOLTAGE AMPLIFICATION  
 VS  
 LOAD RESISTANCE

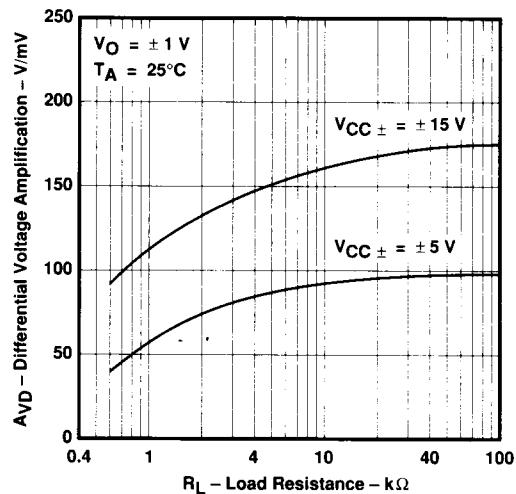


FIGURE 19

LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE SHIFT  
 VS  
 FREQUENCY

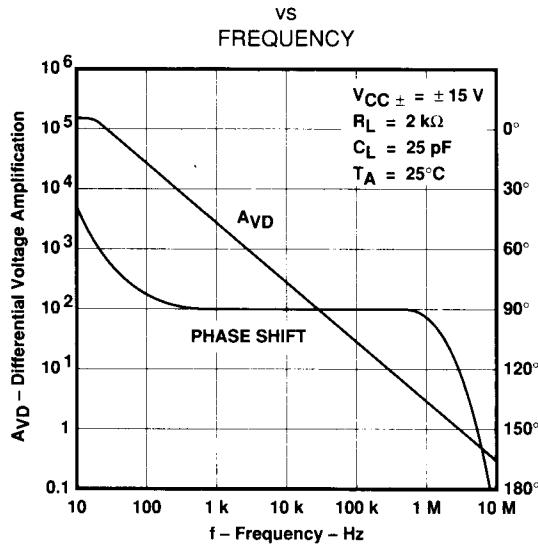


FIGURE 20

LARGE-SIGNAL VOLTAGE AMPLIFICATION  
 VS  
 FREE-AIR TEMPERATURE

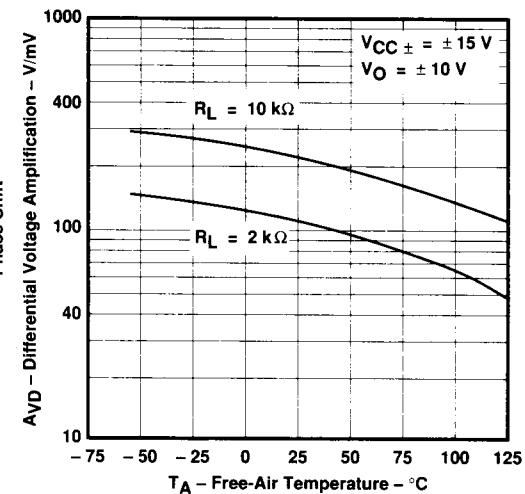


FIGURE 21

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

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**JFET-INPUT OPERATIONAL AMPLIFIERS**

**TYPICAL CHARACTERISTICS<sup>†</sup>**

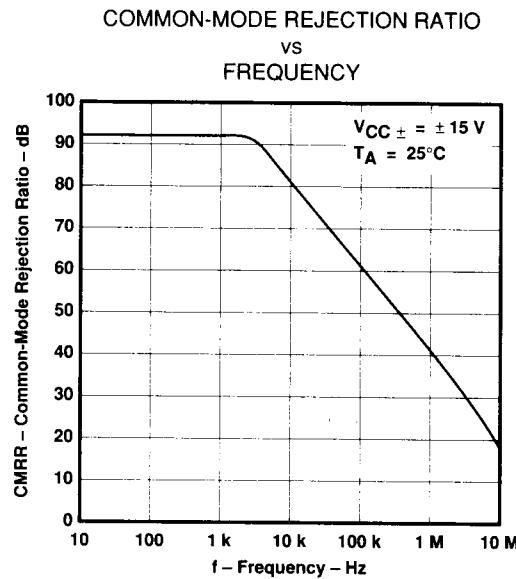


FIGURE 22

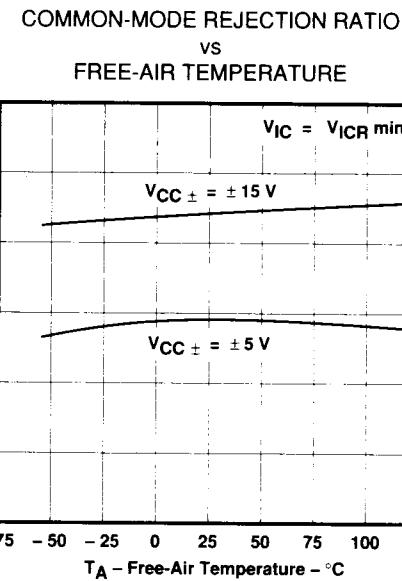


FIGURE 23

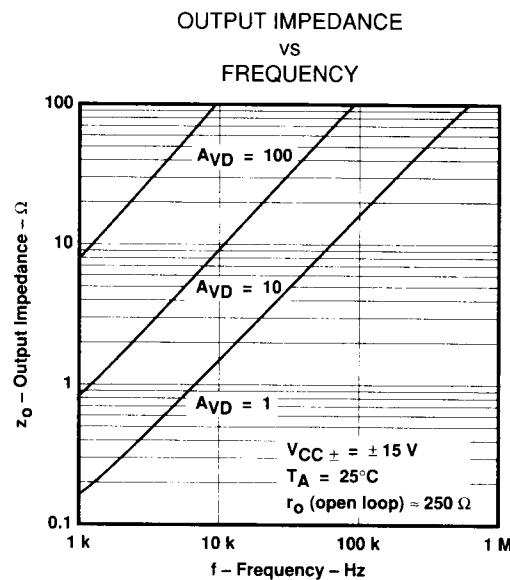


FIGURE 24

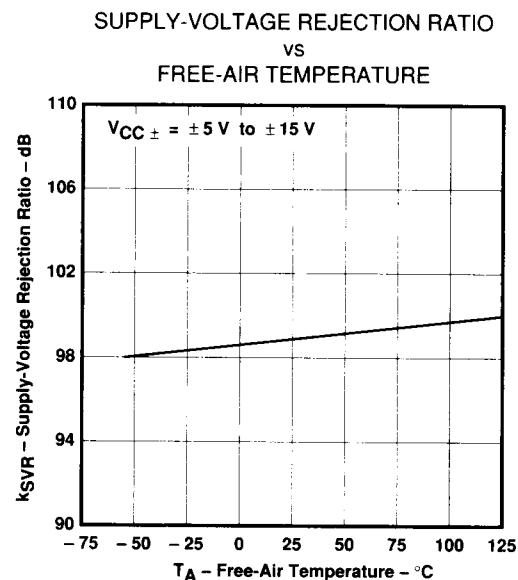


FIGURE 25

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

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**TYPICAL CHARACTERISTICS†**

SHORT-CIRCUIT OUTPUT CURRENT  
 VS  
 SUPPLY VOLTAGE

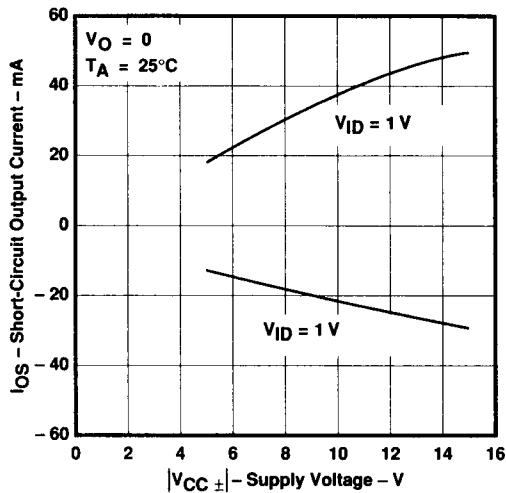


FIGURE 26

SHORT-CIRCUIT OUTPUT CURRENT  
 VS  
 TIME

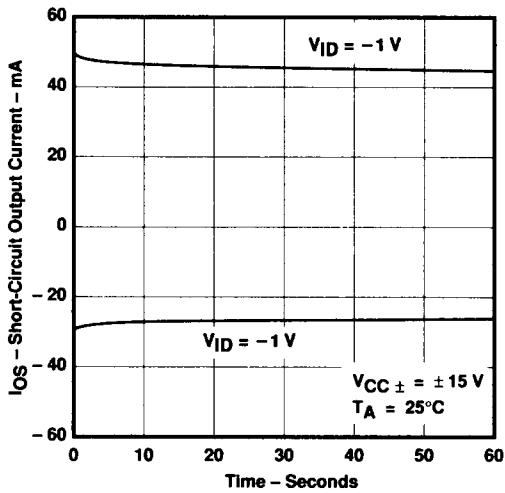


FIGURE 27

SHORT-CIRCUIT OUTPUT CURRENT  
 VS  
 FREE-AIR TEMPERATURE

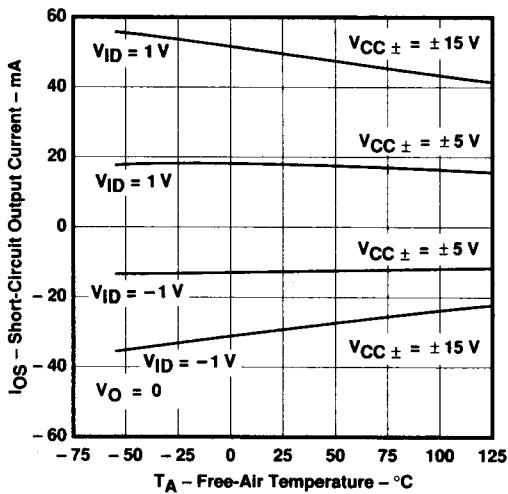


FIGURE 28

†Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

**TL087, TL088, TL287, TL288**  
**JFET-INPUT OPERATIONAL AMPLIFIERS**

**TYPICAL CHARACTERISTICS<sup>†</sup>**

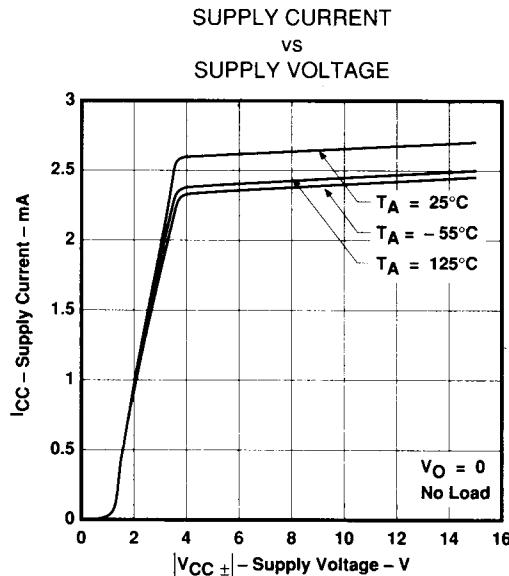


FIGURE 29

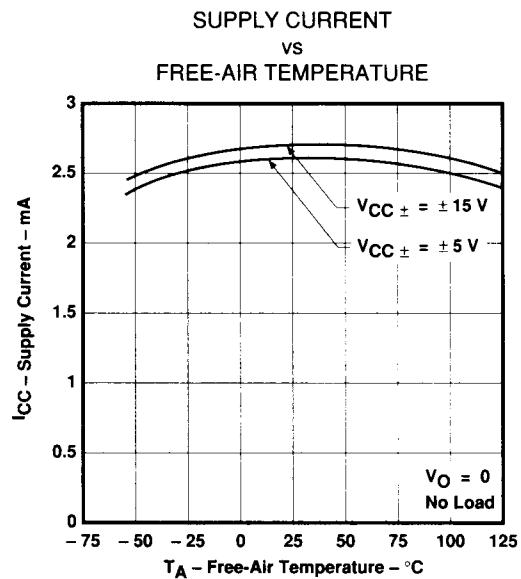


FIGURE 30

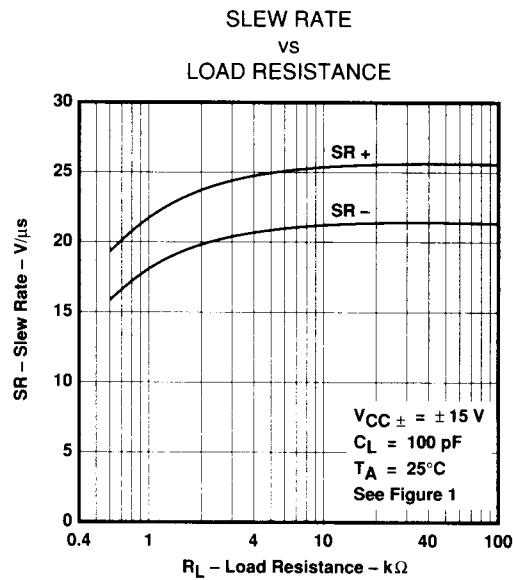


FIGURE 31

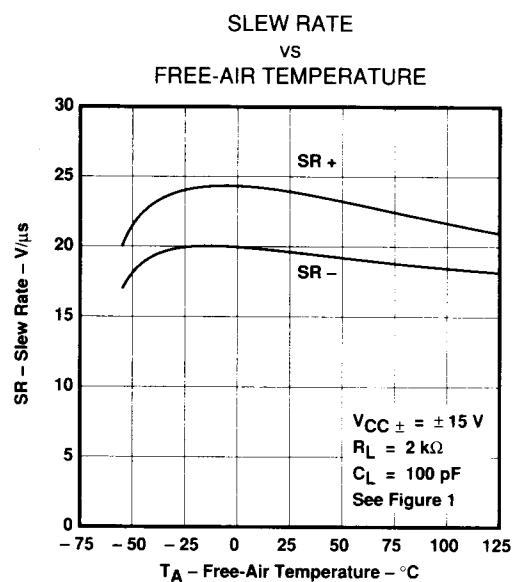


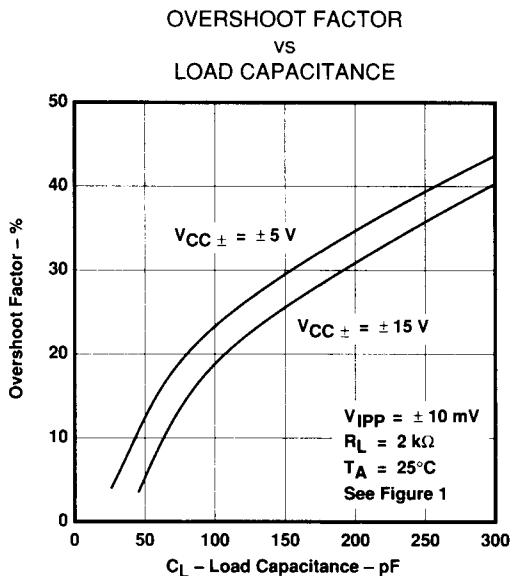
FIGURE 32

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

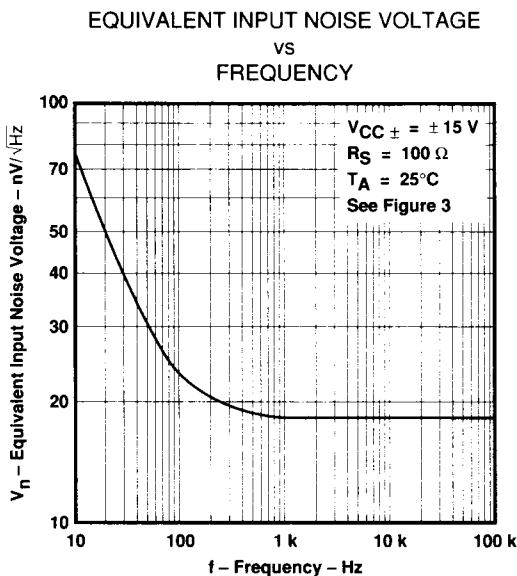
**TEXAS  
INSTRUMENTS**

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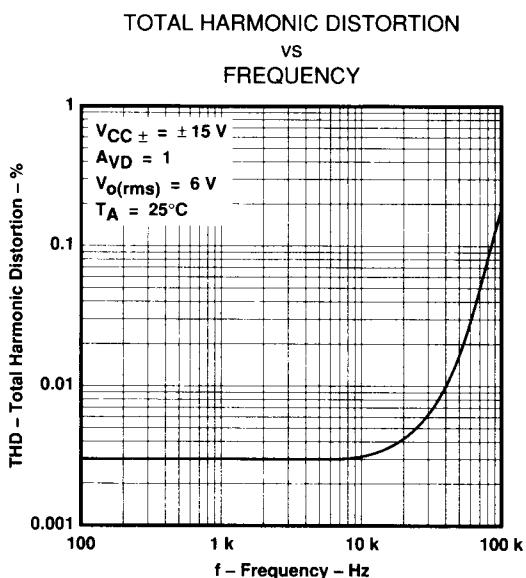
**TYPICAL CHARACTERISTICS<sup>†</sup>**



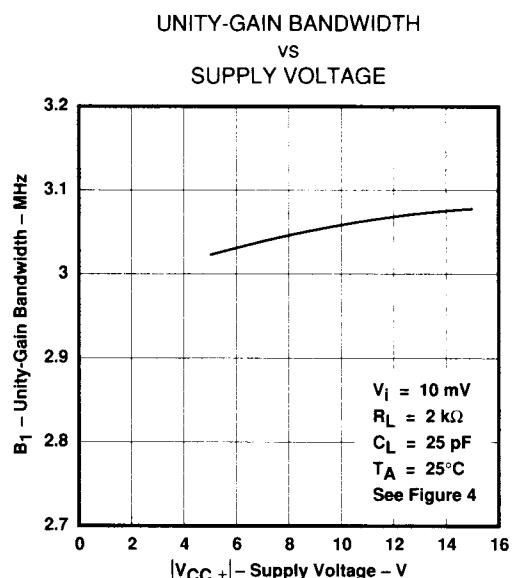
**FIGURE 33**



**FIGURE 34**



**FIGURE 35**



**FIGURE 36**

<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

## TYPICAL CHARACTERISTICS<sup>†</sup>

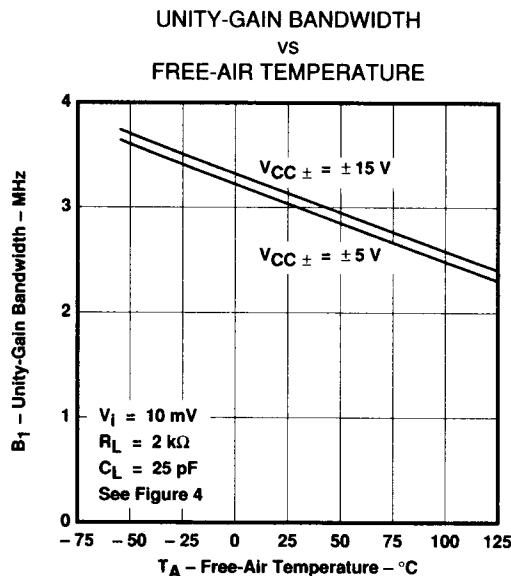


FIGURE 37

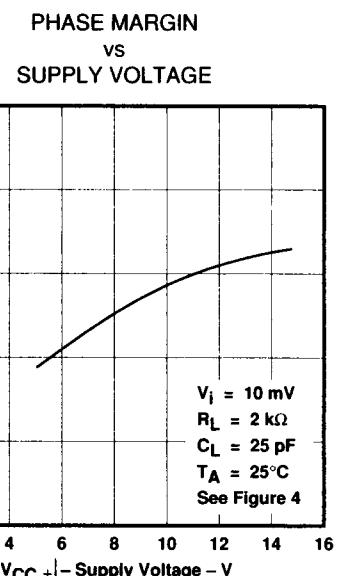


FIGURE 38

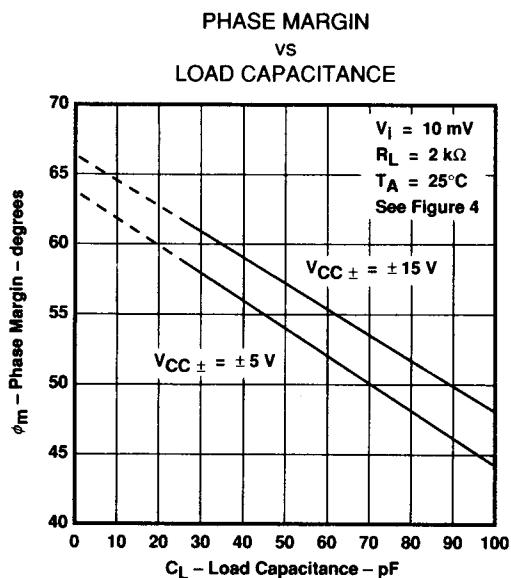


FIGURE 39

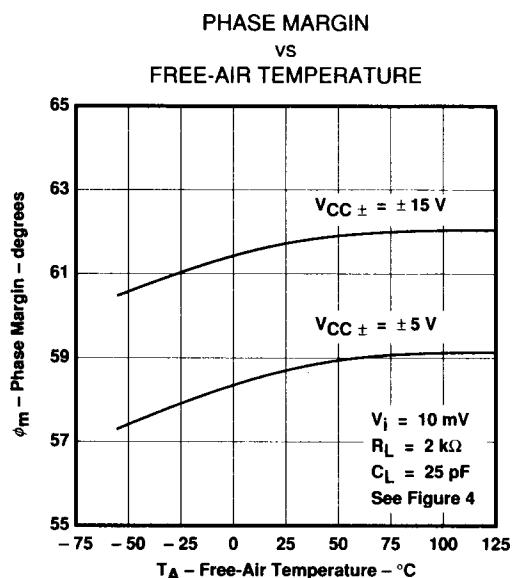


FIGURE 40

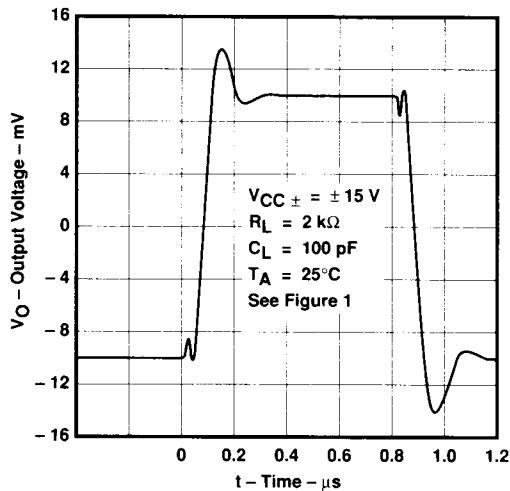
<sup>†</sup>Data at high and low temperatures are applicable within the rated operating free-air temperature ranges of the various devices.

TEXAS  
INSTRUMENTS

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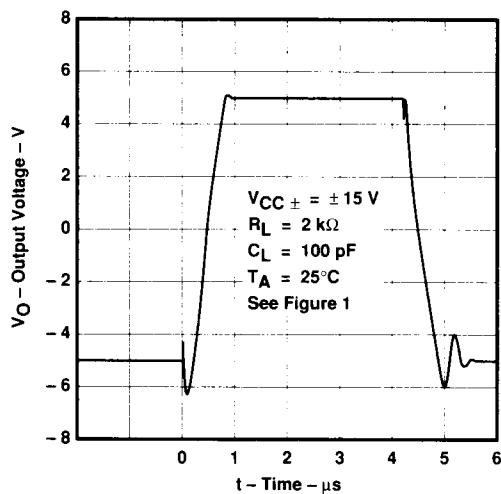
**TYPICAL CHARACTERISTICS**

VOLTAGE-FOLLOWER  
SMALL-SIGNAL  
PULSE RESPONSE



**FIGURE 41**

VOLTAGE-FOLLOWER  
LARGE-SIGNAL  
PULSE RESPONSE



**FIGURE 42**

# TL087, TL088, TL287, TL288 JFET-INPUT OPERATIONAL AMPLIFIERS

## TYPICAL APPLICATION DATA

### output characteristics

All operating characteristics are specified with 100-pF load capacitance. These amplifiers will drive higher capacitive loads; however, as the load capacitance increases, the resulting response pole occurs at lower frequencies, thereby causing ringing, peaking, or even oscillation. The value of the load capacitance at which oscillation occurs varies with production lots. If an application appears to be sensitive to oscillation due to load capacitance, adding a small resistance in series with the load should alleviate the problem. Capacitive loads of 1000 pF and larger may be driven if enough resistance is added in series with the output (see Figure 43).

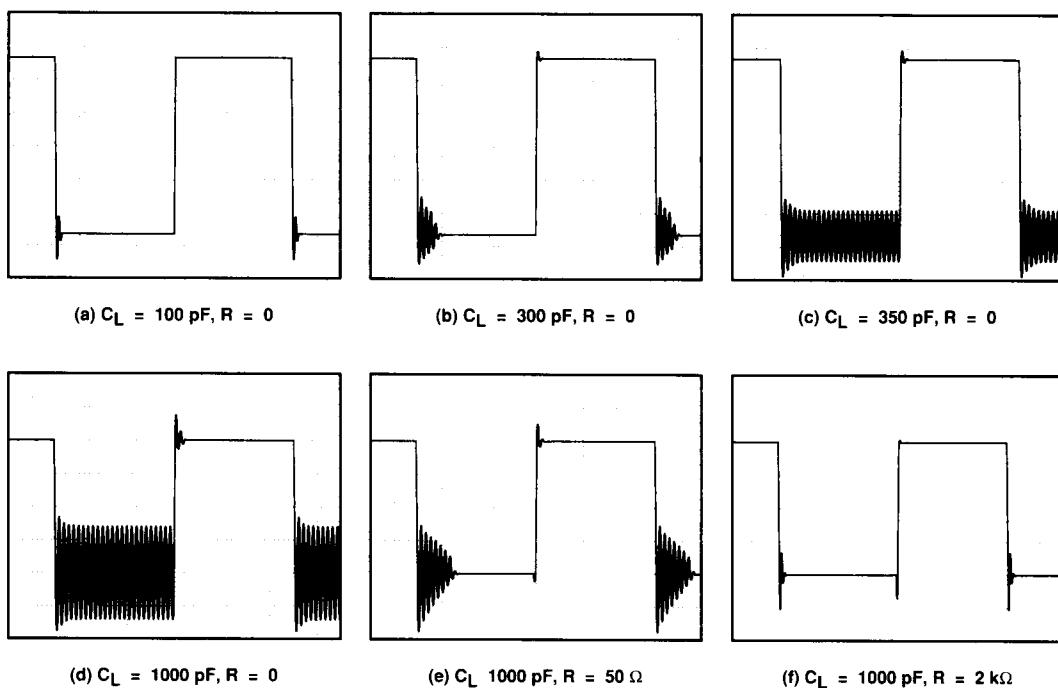
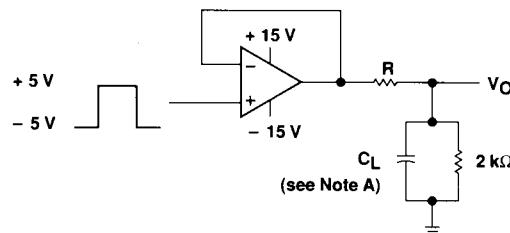


FIGURE 43. EFFECT OF CAPACITIVE LOADS



NOTE A:  $C_L$  includes fixture capacitance.

FIGURE 44. TEST CIRCUIT FOR OUTPUT CHARACTERISTICS

**TEXAS  
INSTRUMENTS**

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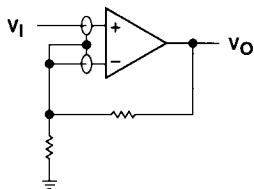
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**TYPICAL APPLICATION DATA**

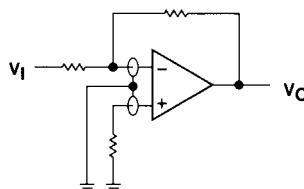
**input characteristics**

These amplifiers are specified with a minimum and a maximum input voltage that, if exceeded at either input, could cause the device to malfunction.

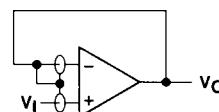
Because of the extremely high input impedance and resulting low bias current requirements, these amplifiers are well suited for low-level signal processing; however, leakage currents on printed circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 45). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.



(a) NONINVERTING AMPLIFIER



(b) INVERTING AMPLIFIER



(c) UNITY-GAIN AMPLIFIER

**FIGURE 45. USE OF GUARD RINGS**

**noise performance**

The noise specifications in op amp circuits are greatly dependent on the current in the first-stage differential amplifier. The low input bias current requirements of these amplifiers result in a very low current noise. This feature makes the devices especially favorable over bipolar devices when using values of circuit impedance greater than 50 k $\Omega$ .